







LSF0002

SDLS975 - APRIL 2024

# LSF0002 Ultra-Small Auto-Bidirectional Translator for Open Drain or Push Pull Applications

#### 1 Features

- Provides bidirectional voltage translation with no direction pin
- Supports up to 100MHz up translation and greater than 100MHz down translation at ≤ 30pF capacitive load and up To 40MHz up or down translation at 50pF capacitive load
- Allows bidirectional voltage-level translation between
  - 0.95V ↔ 1.8/2.5/3.3/5V
  - $1.2V \leftrightarrow 1.8/2.5/3.3/5V$
  - $1.8V \leftrightarrow 2.5/3.3/5V$
  - 2.5V ↔ 3.3/5V
  - $3.3V \leftrightarrow 5V$
- Low standby current
- 5V tolerance I/O port to support TTL
- Low R<sub>ON</sub> provides less signal distortion
- High-impedance I/O pins for EN = Low
- Flow-through pinout for easy PCB trace routing
- Latch-up performance >100mA per JESD 17
- -40°C to 125°C operating temperature range

# 2 Applications

- GPIO, MDIO, PMBus, SMBus, SDIO, UART, I<sup>2</sup>C, and other interfaces in telecom infrastructure
- Enterprise systems
- Communications equipment
- Personal electronics
- Industrial applications

## 3 Description

LSF0002 supports bidirectional The translation without the need for DIR pin, which minimizes system effort (for PMBus, I<sup>2</sup>C, SMBus, and so forth). The LSF family of devices supports up to 100MHz up translation and greater than 100MHz down translation at ≤ 30pF capacitive load and up to 40MHz up or down translation at 50pF capacitive load, which allows the LSF family to support more consumer or telecom interfaces (MDIO or SDIO).

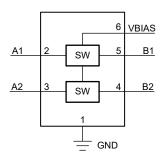
LSF family supports 5V tolerance on I/O port, which makes it compatible with TTL levels in industrial and telecom applications. The LSF family can set up different voltage translation levels, which makes it very flexible.

Unlike the LSF0x0x family, the LSF0002 does not require VREF A and VREF B power supplies and the  $200k\Omega$  bias resistor. The LSF0002 utilizes the  $V_{BIAS}$ pin that enables translation by being biased to the same voltage as the lower power supply at the I/Os that is being translated to and from.

**Package Information** 

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)
LSF0002	DTQ (X2SON, 6)	1mm × 0.8mm

- For more information, see Section 11.
- (2)The package size (length × width) is a nominal value and includes pins, where applicable.



**Functional Block Diagram** 



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# **4 Pin Configuration and Functions**

Pinout drawings are not to scale



Figure 4-1. LSF0002 DTQ Package, 6-Pin X2SON (Top View)

**Table 4-1. Pin Functions** 

PIN		TYPE(1)	DESCRIPTION				
NAME	NO.	IIFE\/	DESCRIPTION				
A1	2	I/O					
A2	3	I/O	Auto Bidirectional Data part				
B1	5	I/O	uto-Bidirectional Data port				
B2	4	I/O					
VBIAS	6	I	Enable input/ Supply Voltage				
GND	1	_	Ground				

(1) I= input, O = output



# 5 Specifications

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

				MIN	MAX	UNIT
VI	Input voltage <sup>(2)</sup>			-0.5	7	V
V <sub>I/O</sub>	Input/output voltage <sup>(2)</sup>	ut/output voltage <sup>(2)</sup>		-0.5	7	V
	Continuous channel current				128	mA
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < (	)		-50	mA
TJ	Junction temperature				150	°C
T <sub>stg</sub>	Storage temperature			-65	150	°C

<sup>(1)</sup> Operation outside the *Absolute Maximum Rating* may cause permanent device damage. *Absolute Maximum Rating* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Condition*. If used outside the *Recommended Operating Condition* but within the *Absolute Maximum Rating*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) The input and input/output voltage ratings may be exceeded if the input and input/output clamp-current ratings are observed.

### 5.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(3)</sup>	±2000	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per AEC Q100-001	±1000	V
V	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V	
V <sub>(ESD)</sub>	Electrostatic discriarge	Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- 2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.
- (3) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	PARAMETER		MIN	MAX	UNIT
V <sub>BIAS</sub>	Reference Voltage		0	5.5	V
V <sub>I/O</sub>	Input/Output voltage	A1, A2, B1, B2	0	5.5	V
I <sub>PASS</sub>	Pass switch current			64	mA
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Product Folder Links: LSF0002



### **5.4 Thermal Information**

		LSF0002	
	THERMAL METRIC(1)	DTQ (X2SON)	UNIT
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	294.4	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	188.9	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	216.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	26.5	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	216.0	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

### 5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST COND	ITIONS	MIN TYP <sup>(1)</sup>	MAX	UNIT	
V <sub>IK</sub>	I <sub>I</sub> = -18mA	EN = 0V			-1.2	V	
I <sub>IH</sub>	V <sub>I</sub> = 5V	EN = 0V			5.0	μΑ	
I <sub>CCBA</sub>	$V_{ref\_B} = V_{EN} = 5$	$5.5V$ , $V_{ref\_A} = 4.5V$ ,	$I_O = 0$ , $V_I = V_{CC}$ or GND	1		μΑ	
C <sub>I(ref_A/B/EN)</sub>	V <sub>I</sub> = 3V or 0			11		pF	
C <sub>io(off)</sub>	$V_0 = 3V \text{ or } 0,$	V <sub>EN</sub> = 0V		4.0	6.0	pF	
C <sub>io(on)</sub>	$V_0 = 3V \text{ or } 0,$	V <sub>EN</sub> = 3V		10.5	12.5	pF	
			$V_{ref\_A}$ = 3.3V; $V_{ref\_B}$ = $V_{EN}$ = 5V	8.0			
	V <sub>I</sub> = 0,	V <sub>I</sub> = 0,	I <sub>O</sub> = 64mA	V <sub>ref_A</sub> = 1.8V; V <sub>ref_B</sub> = V <sub>EN</sub> = 5V	9.0		Ω
			V <sub>ref_A</sub> = 1.0V; V <sub>ref_B</sub> = V <sub>EN</sub> = 5V	10			
	V <sub>1</sub> = 0,	I <sub>O</sub> = 32mA	V <sub>ref_A</sub> = 1.8V; V <sub>ref_B</sub> = V <sub>EN</sub> = 5V	10		Ω	
r <sub>ON</sub> (2)	V <sub>1</sub> – U,	1 <sub>0</sub> – 32111A	V <sub>ref_A</sub> = 2.5V; V <sub>ref_B</sub> = V <sub>EN</sub> = 5V	15		Ω	
	V <sub>I</sub> = 1.8V,	I <sub>O</sub> = 15mA	V <sub>ref_A</sub> = 3.3V; V <sub>ref_B</sub> = V <sub>EN</sub> = 5V	9.0		Ω	
	V <sub>I</sub> = 1.0V,	I <sub>O</sub> = 10mA	$V_{ref\_A} = 1.8V; V_{ref\_B} = V_{EN} = 3.3V$	18		Ω	
	V <sub>I</sub> = 0V,	I <sub>O</sub> = 10mA	$V_{ref\_A} = 1.0V; V_{ref\_B} = V_{EN} = 3.3V$	20		Ω	
	V <sub>I</sub> = 0V,	I <sub>O</sub> = 10mA	$V_{ref\_A} = 1.0V; V_{ref\_B} = V_{EN} = 1.8V$	30		Ω	

<sup>(1)</sup> All typical values are at T<sub>A</sub> = 25°C.

<sup>(2)</sup> Measured by the voltage drop between the A and B pins at the indicated current through the switch. Minimum ON-state resistance is determined by the lowest voltage of the two (A or B) pins.



### 5.6 Switching Characteristics (Translating Down): $B_N = 3.3V$

over recommended operating free-air temperature range,  $B_N = 3.3V$ ,  $B_N = VIH = A_N + 1$ , VIL = 0, and  $VM = 0.5A_N$  (unless otherwise noted) (see *Parameter Measurement Information*)

	PARAMETER	TEST CONDITION	s	MIN	TYP	MAX	UNIT
			C <sub>L</sub> = 15pF		0.3		
T <sub>PLH</sub>	Low-to-high propagation delay		C <sub>L</sub> = 30pF		0.7		ns
		From (input) A or B to (output) B or	C <sub>L</sub> = 50pF		1.1		
		A	C <sub>L</sub> = 15pF		0.4		
T <sub>PHL</sub>	High to low propagation delay		C <sub>L</sub> = 30pF		0.8		ns
			C <sub>L</sub> = 50pF		1.2		

# 5.7 Switching Characteristics (Translating Down): $B_N = 2.5V$

over recommended operating free-air temperature range,  $B_N = 2.5V$ ,  $B_N = VIH = A_N + 1$ , VIL = 0, and  $VM = 0.5A_N$  (unless otherwise noted) (see *Parameter Measurement Information*)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
			C <sub>L</sub> = 15pF		0.35		
T <sub>PLH</sub>	Low-to-high propagation delay		C <sub>L</sub> = 30pF		0.8		ns
		A	C <sub>L</sub> = 50pF		1.2		
			C <sub>L</sub> = 15pF		0.5		
T <sub>PHL</sub>	High to low propagation delay		C <sub>L</sub> = 30pF		1		ns
			C <sub>L</sub> = 50pF		1.3		

# 5.8 Switching Characteristics (Translating Up): $B_N = 3.3V$

over recommended operating free-air temperature range,  $B_N = 3.3V$ ,  $B_N = VT = A_N + 1$ ,  $Vref_A = VIH$ , VIL = 0,  $VM = 0.5A_N$  and RL = 300 (unless otherwise noted) (see *Parameter Measurement Information*)

	PARAMETER	TEST CONDITION	S	MIN	TYP	MAX	UNIT
			C <sub>L</sub> = 15pF		0.4		
T <sub>PLH</sub>	PLH Low-to-high propagation delay		C <sub>L</sub> = 30pF		0.8		ns
			C <sub>L</sub> = 50pF		1		
			C <sub>L</sub> = 15pF		0.4		
T <sub>PHL</sub>	High to low propagation delay		C <sub>L</sub> = 30pF		0.9		ns
			C <sub>L</sub> = 50pF		1		

### 5.9 Switching Characteristics (Translating Up): $B_N = 2.5V$

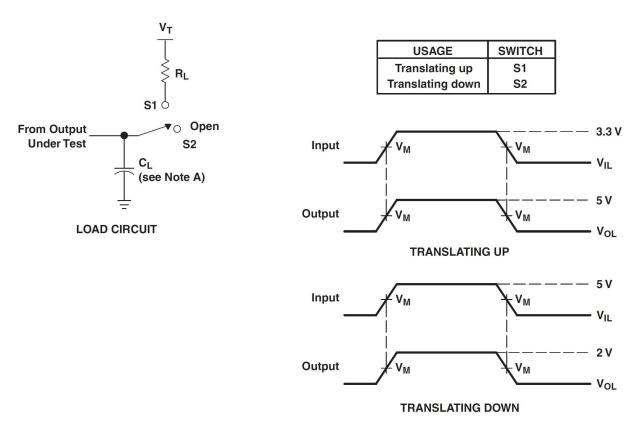
over recommended operating free-air temperature range,  $B_N = 2.5V$ ,  $B_N = VT = A_N + 1$ ,  $A_N = VIH$ , VIL = 0,  $VM = 0.5A_N$  and RL = 300 (unless otherwise noted) (see *Parameter Measurement Information*)

	PARAMETER	TEST CONDITION	S	MIN	TYP	MAX	UNIT
			C <sub>L</sub> = 15pF		0.45		
T <sub>PLH</sub>	T <sub>PLH</sub> Low-to-high propagation delay	From (input) A or B to (output) B or	C <sub>L</sub> = 30pF		0.9		ns
			C <sub>L</sub> = 50pF		1.1		
			C <sub>L</sub> = 15pF		0.6		
T <sub>PHL</sub>	High to low propagation delay		C <sub>L</sub> = 30pF		1.1		ns
			C <sub>L</sub> = 50pF		1.3		

Product Folder Links: LSF0002



# **6 Parameter Measurement Information**



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Generators that have the following characteristics generate all input pulses: PRR  $\leq$  10MHs,  $Z_0$  = 50 $\Omega$ ,  $t_f \leq$  2ns,  $t_f \leq$  2ns.
- C. The outputs are measured one at a time, with one transition per measurement.

Figure 6-1. Load Circuit for Outputs

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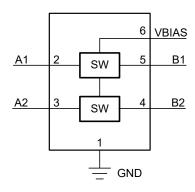


# 7 Detailed Description

### 7.1 Overview

The LSF0002 can be used in level-translation applications for interfacing devices or systems operating with one another that operate at different interface voltages. The LSF family is an excellent choice for use in applications where an open-drain driver is connected to the data I/Os. With appropriate pull-up resistors and layout, LSF can achieve 100MHz. The LSF family can also be used in applications where a push-pull driver is connected to the data I/Os. For an overview of device setup and operation, see *The Logic Minute* training series on *Understanding the LSF Family of Bidirectional, Multi-Voltage Level Translators*.

### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Auto Bidirectional Voltage Translation

The LSF family is an auto bidirectional voltage level translator that is operational from 0.95 to 5.5V. This allows for bidirectional voltage translation between 0.95V and 5.5V without the need for a direction pin in open-drain or push-pull applications. The LSF family supports level translation applications with transmission speeds greater than 100Mbps for open-drain systems using a 30pF capacitance and  $250\Omega$  pullup resistor. Both the output driver of the controller and the peripheral device output can be push-pull or open-drain (pull-up resistors may be required). In both up and down translation, the B-side is often referred to as the high side and refers to devices connected to the B ports. The A-side can be referred to as the low side.



### 7.3.2 V<sub>BIAS</sub>/ Enable

To enable the I/O pins, the  $V_{BIAS}$  input should be referenced towards the lower power supply (in the following example,  $V_{EXT,A}$ ) during voltage translation. To be in the high impedance state during power-up, power-down, or during operation, the  $V_{BIAS}$  pin must be pulled low and at GND or disabled by an open-drain driver without a pullup resistor. Use the  $V_{BIAS}$  pin to properly bias the I/O channels. A filter capacitor on  $V_{BIAS}$  is also recommended for a stable supply at the device.

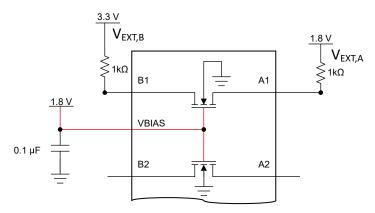


Figure 7-1. V<sub>BIAS</sub> Tied to Lower Power Supply

The supply voltage of open drain I/O devices can be completely different from the supplies used for the LSF and has no impact on the operation. For additional details on how to use the enable pin, see the *Using the Enable Pin with the LSF Family video*.

Table 7-1. Enable Pin Function Table

INPUT V <sub>BIAS</sub> PIN	Data Port State				
Tied directly to V <sub>BIAS</sub>	An = Bn				
L	Hi-Z				

#### 7.4 Device Functional Modes

For each channel (n), when either the An or Bn port is LOW, the switch provides a low impedance path between the An and Bn ports; the corresponding Bn or An port will be pulled LOW. The low R<sub>ON</sub> of the switch allows connections to be made with minimal propagation delay and signal distortion.

Table 7-1 provides a summary of device operation. For additional details on the functional operation of the LSF family of devices, see the *Down Translation with the LSF Family* and *Up Translation with the LSF Family* videos.

Table 7-2. Device Functionality

Signal Direction <sup>(1)</sup>	Input State	Switch State	Functionality
B to A (Down Translation)	B = LOW	ON (Low Impedance)	A-side voltage is pulled low through the switch to the B-side voltage
B to A (Down Translation)	B = HIGH	OFF (High Impedance)	A-side voltage is clamped at V <sub>EXT,A</sub> <sup>(2)</sup>
A to B (Up Translation)	A = LOW	ON (Low Impedance)	B-side voltage is pulled low through the switch to the A-side voltage
A to b (op Translation)	A = HIGH	OFF (High Impedance)	B-side voltage is clamped at $V_{\text{EXT,A}}$ and then pulled up to the $V_{\text{EXT,B}}$ supply voltage

- (1) The downstream channel should not be actively driven through a low impedance driver, or else bus contention may occur.
- (2) The A-side can have a pullup to V<sub>EXT,A</sub> for additional current drive capability or may also be pulled above V<sub>EXT,A</sub> with a pullup resistor. Specifications in the *Recommended Operating Conditions* section should always be followed.



# 8 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The LSF devices can perform voltage translation for open-drain or push-pull interfaces. Table 8-1 provides common interfaces and the corresponding device recommendation from the LSF family, which supports the corresponding bit count.

**Table 8-1. Voltage Translator for Common Interfaces** 

Part Name Channel Number		Interface				
LSF0002	2	GPIO, MDIO, SMBus, PMBus, and I <sup>2</sup> C				

Some important reminders regarding the LSF0002 are as follows:

- LSF devices are switch-based, not buffer-based (for more information, see the TXB family for buffer-based devices).
- Specific data rates cannot be calculated by using 1/Tpd.
- $V_{\text{EXT,A}}/V_{\text{EXT,B}}$  are referenced to the external power supplies at the I/Os.
- V<sub>BIAS</sub> should be tied towards the lowest voltage being translated to at the I/Os.

## 8.2 Typical Applications

# 8.2.1 Open-Drain Interface (I<sup>2</sup>C, PMBus, SMBus, and GPIO)

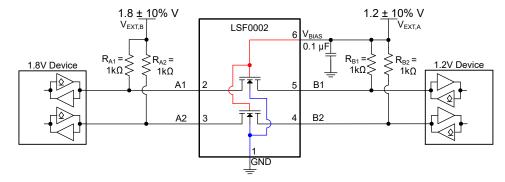


Figure 8-1. Typical Application Circuit for Open-Drain Translation (MDIO Shown as an Example)

#### 8.2.1.1 Design Requirements

#### 8.2.1.1.1 Enable and Disable Guidelines

In the previous figure,  $V_{BIAS}$  is referenced to the lower power supply ( $V_{EXT,A}$ ) of 1.8V power supply and  $V_{EXT,B}$ is set to 3.3V. The A1 and A2 channels have a maximum output voltage equal to V<sub>EXTA</sub> and the B1 and B2 channels have a maximum output voltage equal to V<sub>EXT.B</sub>.

The LSF0002 has an V<sub>BIAS</sub> input that is used to disable the device by driving this node LOW to GND, placing all I/Os in the high-impedance state. Since the LSF family of devices are switch-type voltage translators, the power consumption is very low. TI recommends always enabling the LSF family for bidirectional applications (I<sup>2</sup>C, SMBus, PMBus, or MDIO).

**Table 8-2. Application Operating Condition** 

	PARAMETER	MIN	TYP MAX	UNIT
V <sub>EXT,A</sub> (1)	reference voltage (A)	0.9	5.5	V
V <sub>EXT,B</sub>	reference voltage (B)	V <sub>EXT,A</sub> + 0.8	5.5	V
V <sub>BIAS</sub>	input voltage on V <sub>BIAS</sub> pin	V <sub>EXT,A</sub>	V <sub>EXT,A</sub> + 0.8	V
V <sub>PU</sub>	pull-up supply voltage	0	$V_{EXT,B}$	V

V<sub>EXT.A</sub> is required to be the lowest voltage level across all inputs and outputs.

Note

The  $200k\Omega$ , bias resistor is not required for the LSF0002.

#### 8.2.1.2 Detailed Design Procedure

#### 8.2.1.2.1 Bidirectional Translation

For the bidirectional translation configuration (higher voltage to lower voltage or lower voltage to higher voltage), the V<sub>BIAS</sub> input must be connected to V<sub>EXT.A</sub>. This allows V<sub>BIAS</sub> to regulate the bias of the I/O channels for proper translation. A filter capacitor on V<sub>BIAS</sub> is recommended for a stable supply at the device. The controller output driver can be push-pull or open-drain (pull-up resistors may be required) and the peripheral device output can be push-pull or open-drain (pull-up resistors are required to pull the Bn outputs to VPI).

#### Note

If either output is push-pull, data must be unidirectional or the outputs must be tri-state and be controlled by some direction-control mechanism to prevent HIGH-to-LOW bus contention in either direction. If both outputs are open-drain, no direction control is needed.

#### 8.2.1.2.2 Pull-Up Resistor Sizing

The pull-up resistor value needs to limit the current through the pass transistor when it is in the ON state to about 15mA. Doing this causes a voltage drop of 260mV to 350mV to have a valid LOW signal on the downstream channel. If the current through the pass transistor is higher than 15mA, then the voltage drop is also higher in the ON state. To set the current through each pass transistor at 15mA, calculate the pull-up resistor value using the following equation:

$$Rpu = \frac{(Vpu - 0.35 V)}{0.015 A} \tag{1}$$

Table 8-3 provides resistor values, reference voltages, and currents at 8mA, 5mA, and 3mA. The resistor value shown in the +10% column (or a larger value) should be used so that the voltage drop across the transistor is 350mV or less. The external driver must be able to sink the total current from the resistors on both sides of the LSF family device at 0.175V, although the 15mA applies only to current flowing through the LSF family device. The device driving the low state at 0.175V must sink current from one or more of the pull-up resistors and maintain V<sub>OL</sub>. A decrease in resistance will increase current, and thus result in increased V<sub>OL</sub>.



	Table 6-3. Pull-Op Resistor Values										
V <sub>PU</sub> <sup>(1) (2)</sup>	8n	nA	5n	nA	3mA						
<b>V</b> PU (1) (2)	NOMINAL (Ω)	+10% <sup>(3)</sup> (Ω)	NOMINAL (Ω)	+10% <sup>(3)</sup> (Ω)	NOMINAL (Ω)	+10% <sup>(3)</sup> (Ω)					
5V	V 581 639		581 639 930 1023		1550	1705					
3.3V	369	406	590	649	983	1082					
2.5V	269	296	430	473	717	788					
1.8V	181	199	290	319	483	532					
1.5V	1.5V 144 158		230	253	383	422					
1 2\/	106	117	170	107	202	212					

Table 8-3. Pull-Up Resistor Values

- (1) Calculated for V<sub>OL</sub> = 0.35V
- (2) Assumes output driver V<sub>OL</sub> = 0.175V at stated current
- (3) +10% to compensate for V<sub>DD</sub> range and resistor tolerance

#### 8.2.1.3 Application Curve

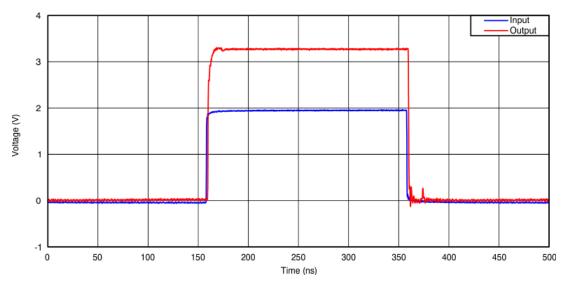


Figure 8-2. Open Drain Translation (1.8V to 3.3V at 2.5MHz)

#### 8.2.2 Mixed-Mode Voltage Translation

The supply voltage ( $V_{\text{EXT A,B}}$ ) for each channel can be individually set with a pull-up resistor. Figure 8-3 shows an example of this mixed-mode multi-voltage translation. For additional details on multi-voltage translation, see the *Multi-voltage Translation with the LSF Family* video.

With  $V_{\text{EXT,B}}$  pulled up to 5V and  $V_{\text{EXT,A}}$  connected to 1.2V, all channels will be clamped to 1.2V at which point a pullup can be used to define the high level voltage for a given channel.

- Push-Pull Down Translation (5V to 1.2V): Channel 1 is an example of this setup. When A2 is 5V, B1 is clamped to 1.2V, and when A1 is LOW, B1 is driven LOW through the switch.
- Push-Pull Up Translation (1.2V to 3.3V): Channel 2 is an example of this setup. When B2 is 1.2V, the switch is high impedance and the A2 channel is pulled up to 3.3V. When B2 is LOW, A2 is driven LOW through the switch.
- Push-Pull Down Translation (3.3V to 1.2V): Channels 2 is an example of this setup. When A2 is driven to 3.3V, B2 is clamped to 1.2V, and when A2 is LOW, B2 is driven LOW through the switch.



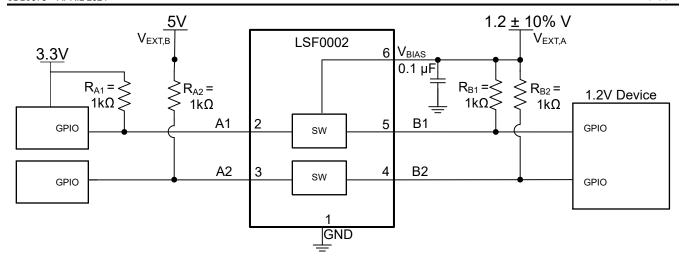


Figure 8-3. Multi-Voltage Translation Example with the LSF Translators

# 8.2.3 Voltage Translation for $V_{ref\ B} < V_{ref\ A} + 0.8V$

As described in the *Enable and Disable Guidelines* section, it is generally recommended that  $V_{EXT,B} > V_{EXT,A} + 0.8V$ ; however, the device can still operate in the condition where  $V_{EXT,B} < V_{EXT,A} + 0.8V$  as long as additional considerations are made for the design.

**Typical Operation (V**<sub>EXT,B</sub> > V<sub>EXT,A</sub> + 0.8V): in this scenario, pullup resistors are not required on the A-side for proper down-translation. When down translating from B to A, the A-side I/O ports will clamp at V<sub>EXT,A</sub> to provide proper voltage translation. For further explanation of device operation, see the *Down Translation with the LSF Family* video.

**Requirements for V**<sub>EXT,B</sub> < **V**<sub>EXT,A</sub> + **0.8V Operation:** in this scenario, there is not a large enough voltage difference between V<sub>EXT,A</sub> and V<sub>EXT,B</sub> so that the A side I/O ports will be clamped at V<sub>EXT,A</sub>, but rather at a voltage approximately equal to V<sub>EXT,B</sub> – 0.8V. For example, if V<sub>EXT,B</sub> = 1.8V and V<sub>EXT,A</sub> = 1.2V, the A-side I/Os will clamp to a voltage around 1.0V. Therefore, to operate in such a condition, the following additional design considerations must be met:

- $V_{EXT,B}$  must be greater than  $V_{EXT,A}$  during operation ( $V_{EXT,B} > V_{EXT,A}$ )
- Pullup resistors should be populated on A-side I/O ports for the line to be fully pulled up to the desired voltage.

Figure 8-4 shows an example of this setup, where  $1.2V \leftrightarrow 1.8V$  translation is achieved with the LSF0002. This type of setup also applies for other voltage nodes such as  $1.8V \leftrightarrow 2.5V$ ,  $1.05V \leftrightarrow 1.5V$ , and others as long as the *Recommended Operating Conditions* table is followed.



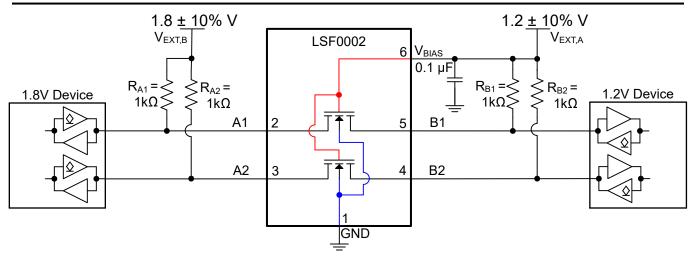


Figure 8-4. 1.2V to 1.8V Level Translation with LSF0002

# 8.3 Power Supply Recommendations

There are no power sequence requirements for the LSF family. Table 8-4 provides recommended operating voltages for all supply and input pins.

**Table 8-4. Recommended Operating Voltages** 

			•	
	PARAMETER	MIN	TYP MAX	UNIT
V <sub>EXT,A</sub> (1)	reference voltage (A)	0.9	5.5	V
V <sub>EXT,B</sub>	reference voltage (B)	V <sub>EXT,A</sub> + 0.8	5.5	V
V <sub>BIAS</sub>	input voltage on EN pin	V <sub>EXT,A</sub>	V <sub>EXT,A</sub> + 0.8	V
V <sub>PU</sub>	pull-up supply voltage	0	$V_{EXT,B}$	V

<sup>(1)</sup>  $V_{\text{EXT,A}}$  is required to be the lowest voltage level across all inputs and outputs.

#### 8.4 Layout

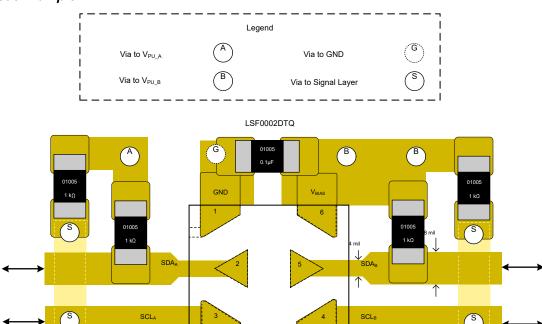
#### 8.4.1 Layout Guidelines

Because the LSF family is a switch-type level translator, the signal integrity is highly related with a pull-up resistor and PCB capacitance condition. Therefore, do as follows:

- Short the signal trace as short as possible to reduce capacitance and minimize stub from the pull-up resistor.
- Place the LSF device as close to the high voltage side as possible.
- Select the appropriate pull-up resistor that applies to translation levels and the driving capability of the transmitter.



# 8.4.2 Layout Example



\*Pullup Resistors are not required to be adjacent to the device, and can be present on the I<sup>2</sup>C line elsewhere in the system

Figure 8-5. Short Trace Layout



Figure 8-6. Device Placement

Submit Document Feedback



# 9 Device and Documentation Support

### 9.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, LSF Translator Family Evaluation Module user's guide
- Texas Instruments, Biasing Requirements for TXS, TXB, and LSF Auto-Bidirectional Translators application note
- Texas Instruments, Voltage Level Translation with the LSF Family application note
- The Logic Minute Video Training Series on Understanding the LSF Family of Devices:
  - Texas Instruments, Introduction Voltage Level Translation with the LSF Family
  - Texas Instruments, Understanding the Bias Circuit for the LSF Family
  - Texas Instruments, Using the Enable Pin with the LSF Family
  - Texas Instruments, Translation Basics with the LSF Family
  - Texas Instruments, Down Translation with the LSF Family
  - Texas Instruments, Up Translation with the LSF Family
  - Texas Instruments, Multi-Voltage Translation with the LSF Family
  - Texas Instruments, Single Supply Translation with the LSF Family

### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 9.4 Trademarks

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#### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

# 10 Revision History

DATE	REVISION	NOTES
April 2024	*	Initial Release

# 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 24-Jul-2025

#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
LSF0002DTQR	Active	Production	X2SON (DTQ)   6	12000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	J
LSF0002DTQR.A	Active	Production	X2SON (DTQ)   6	12000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	J
LSF0002DTQR.B	Active	Production	X2SON (DTQ)   6	12000   LARGE T&R	-	NIPDAU	Level-1-260C-UNLIM	-40 to 125	J

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 25-Sep-2024

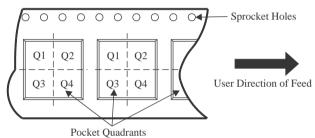
### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LSF0002DTQR	X2SON	DTQ	6	12000	180.0	8.4	0.92	1.12	0.47	4.0	8.1	Q2

www.ti.com 25-Sep-2024

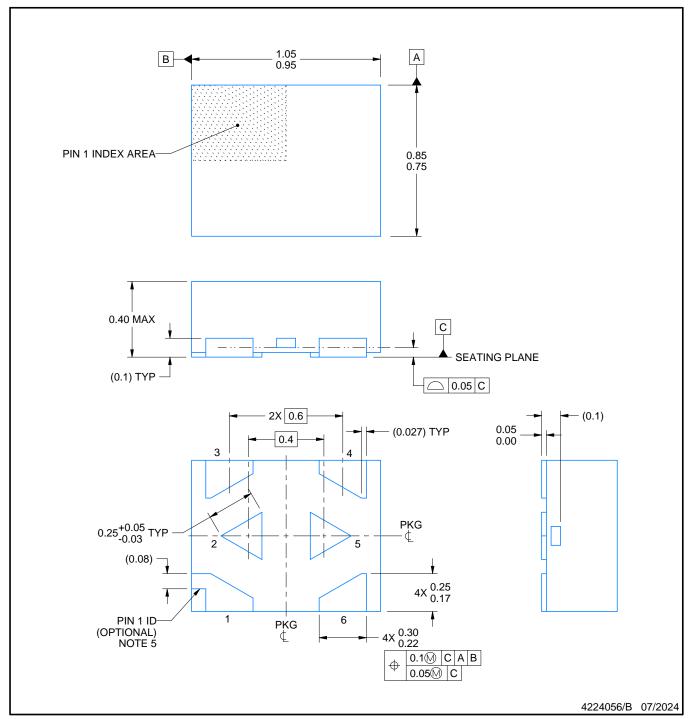


### \*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	LSF0002DTQR	X2SON	DTQ	6	12000	182.0	182.0	20.0	



PLASTIC SMALL OUTLINE - NO LEAD



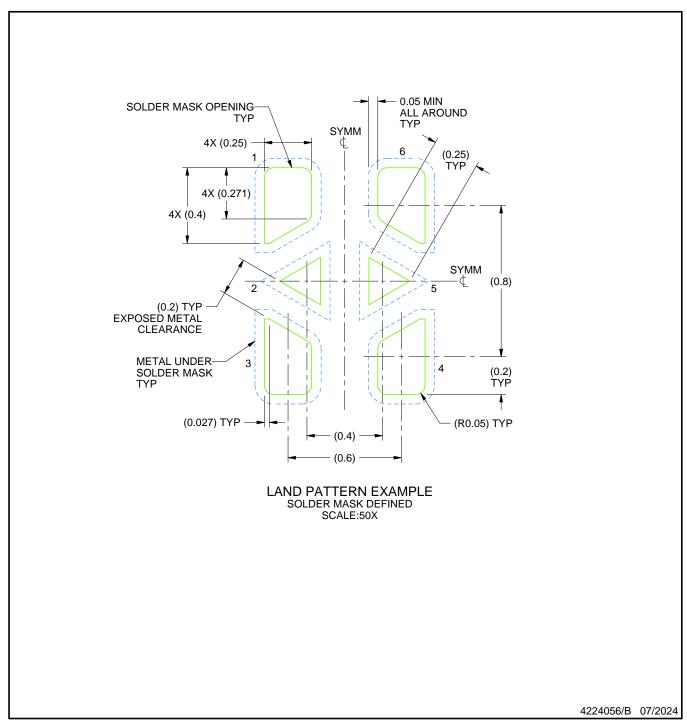
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pads must be soldered to the printed circuit board for optimal thermal and mechanical performance.

  4. The size and shape of this feature may vary.
- 5. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.



PLASTIC SMALL OUTLINE - NO LEAD



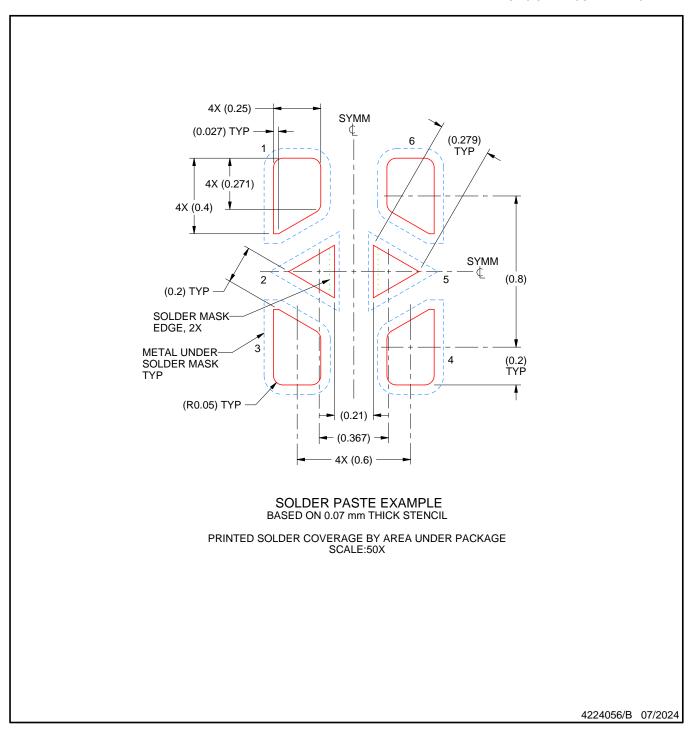
NOTES: (continued)



<sup>6.</sup> This package is designed to be soldered to a thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

<sup>7.</sup> Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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